L Number	Hits	Search Text	DB	Time stamp
6	4114	((1257/757) or (257/773) or (257/736) or (257/736) or (257/741) or (257/750) or (257/758) or (257/765) or (438/688) or (438/643) or (438/648) or (257/757) or (257/759) or (257/759) or (257/765) or (257/771)).CCLS.) and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/15 13:15
9	320	ardurnum 'ead<=19990908 and 'polycrystal' with 'aluminum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 13:16
10	437	@ad<=19990908 and (438/652).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 13:51
-	2	("6214723").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/02 12:50
-	1	"5270255".PN.	USPAT	2002/07/18 07:59
-	1	"5459353".PN.	USPAT	2002/07/18 07:59
-	1	"5844318".PN.	USPAT	2002/07/18 08:01
-	1	"5278449".PN.	USPAT	2002/07/18 08:01
-	1	"5341026".PN.	USPAT	2002/07/18 08:02
-	1	"5567987".PN.	USPAT	2002/07/18
-	1	"5459353".PN. "5523259".PN.	USPAT	2002/07/18 08:02 2002/07/18
	1	"5572072".PN.	USPAT	08:02 2002/07/18
_	1	"5844318".PN.	USPAT	08:02 2002/07/18
-	0	@ad<=19990908 and 'conductive layer' with 'Alumium' with 'recess'	USPAT; US-PGPUB; EPO; JPO;	08:02 2002/07/18 08:34
-	4	@ad<=19990908 and 'conductive layer' with 'Al' with 'recess'	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/07/18
-	51	@ad<=19990908 and 'conductive layer' with 'crystal grain'	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/07/18 09:48
-	1	"4639277".PN.	IBM_TDB USPAT	2002/07/18 08:23
-	1	"4693759".PN.	USPAT	2002/07/18
-	1	"4837183".PN.	USPAT	2002/07/18 08:23
-	1	"5028550".PN.	USPAT	2002/07/18
-	1	"5084403".PN.	USPAT	2002/07/18
-	1	"5084403".PN.	USPAT	2002/07/18 08:24
-	1	"4566175".PN.	USPAT	2002/07/18

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	1	"4613956".PN.		
	1		USPAT	2002/07/18 08:25
-	1	"4613956".PN.	USPAT	2002/07/18
-	1	"5256894".PN.	USPAT	2002/07/18
-	1	"4613956".PN.	USPAT	08:26 2002/07/18
-	494	@ad<=19990908 and (257/755).ccls.	USPAT;	08:26 2003/09/15
			US-PGPUB; EPO; JPO; DERWENT; IBM TDB	13:49
-	292	@ad<=19990908 and 'low temperature' near 'aluminum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/18
-	1357	@ad<=19990908 and 'interconnection' near 'aluminum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/18 08:43
-	110	(@ad<=19990908 and 'interconnection' near 'aluminum') and 'low temperature' and 'high temperature'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/18 09:20
-	10	@ad<=19990908 and 'low temperature aluminum' and 'high temperature aluminum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/18 09:23
-	1333	@ad<=19990908 and (257/773).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/07/18 10:22
=	3	<pre>@ad<=19990908 and 'conductive layer' with 'polycrystal grain'</pre>	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/26 15:59
-	12	<pre>@ad<=19990908 and 'conductive layer' with 'crystal grain boundary'</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/18 11:59
-	3429	((257/736) or (257/741) or (257/750) or (257/758) or (257/765) or (257/771)).ccus.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/27 10:35
-	1489	(((257/736) or (257/741) or (257/750) or (257/758) or (257/765) or (257/771)).ccLs.) and @ad<=19990908 and 'aluminum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/27 10:35
-	30	@ad<=19990908 and 'polycrystal' near 'aluminum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/18 12:01
-	323	@ad<=19990908 and 'polycrystal' with 'aluminum'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/15 13:15
-	1	"5270255".PN.	USPAT	2002/11/26
-	1	"5270255".PN.	USPAT	15:25 2002/11/26 15:25

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-	1	"5459353".PN.	USPAT	T 2002 (11 (26
	1	3439333 .PN.	USPAT	2002/11/26
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-	1	"5523259".PN.	USPAT	2002/11/26
	1			15:25
-	1	"5844318".PN.	USPAT	2002/11/26
	1			15:26
-	2	@ad<=19990908 and 'conductive layer' same	USPAT:	2002/11/26
		'recess' same 'crystal grain'	US-PGPUB;	16:00
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	7143	((257/757) or (257/773) or (257/736) or	USPAT:	0000 (4.1./05
	/143	(257/741) or (257/750) or (257/758) or		2002/11/27
			US-PGPUB;	10:38
		(257/765) or (438/688) or (438/643) or	EPO; JPO;	1
		(438/648) or (257/757) or (257/758) or	DERWENT;	
		(257/765) or (257/771)).CCLS.	IBM_TDB	
-	3586		USPAT;	2003/09/15
	1	(257/741) or (257/750) or (257/758) or	US-PGPUB;	13:13
	1	(257/765) or (438/688) or (438/643) or	EPO; JPO;	1
	1	(438/648) or (257/757) or (257/758) or	DERWENT;	
	[(257/765) or (257/771)).CCLs.) and	IBM TDB	1
	1	'aluminum'	1211_100	1
_	1		USPAT;	2222 (23 (25
	1	4031004 .PM.		2002/11/27
	7.0		US-PGPUB	10:51
-	762		USPAT;	2002/11/27
	1	(257/741) or (257/750) or (257/758) or	US-PGPUB;	10:52
		(257/765) or (438/688) or (438/643) or	EPO; JPO;	
		(438/648) or (257/757) or (257/758) or	DERWENT;	1
	1	(257/765) or (257/771)).CCLS.) and	IBM TDB	
		'aluminum') and 'crystal'	-	
-	128	((((257/757) or (257/773) or (257/736) or	USPAT;	2002/11/27
		(257/741) or (257/750) or (257/758) or	US-PGPUB;	10:53
	1	(257/765) or (438/688) or (438/643) or	EPO; JPO;	10.00
		(438/648) or (257/757) or (257/758) or	DERWENT;	
		(257/765) or (257/771)).CCLS.) and	IBM TDB	
	1		IBM_TDB	
	245	'aluminum') and 'crystal' same 'boundary'	l	
-	245		USPAT;	2002/12/02
	1	'glass' and @ad<=19990908	US-PGPUB;	12:58
	1		EPO; JPO;	Į.
			DERWENT;	1
	1		IBM TDB	
_	2	'solar cell' same 'silicon substrate'	USPAT;	2002/12/02
	1	near 'glass' and @ad<=19990908	US-PGPUB;	13:24
	1	9 0 13330300	EPO; JPO;	1
			DERWENT;	1
	1		IBM TDB	1
_	3	("4419533").PN.	USPAT:	2002/12/02
] 3	(441233).PN.		
	1		US-PGPUB;	13:25
	1		EPO; JPO;	1
			DERWENT;	1
			IBM_TDB	
-	3	(("4532372") or ("4598306")).PN.	USPAT;	2002/12/02
			US-PGPUB;	13:25
	1		EPO; JPO;	1
			DERWENT;	1
			IBM TDB	I